MSA-0520

Cascadable Silicon Bipolar MMIC Amplifier



Data Sheet

Description

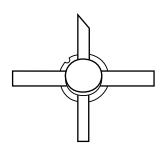
The MSA-0520 is a high performance silicon bipolar Monolithic Microwave Integrated Circuit (MMIC) housed in a hermetic, BeO disk package for good thermal characteristics. This MMIC is designed for use as a general purpose 50Ω gain block. Typical applications include narrow and broad band IF and RF amplifiers in industrial and military applications.

The MSA-series is fabricated using Avago's 10 GHz f_T , 25 GHz f_{MAX} , silicon bipolar MMIC process which uses nitride self-alignment, ion implantation, and gold metallization to achieve excellent performance, uniformity and reliability. The use of an external bias resistor for temperature and current stability also allows bias flexibility.

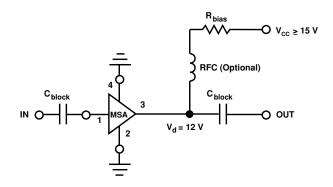
Features

- Cascadable 50 Ω Gain Block
- High Output Power: +23 dBm Typical P_{1 dB} at 1.0 GHz
- Low Distortion:
 33 dBm Typical IP₃ at 1.0 GHz
- 8.5 dB Typical Gain at 1.0 GHz
- Hermetic Metal/Beryllia Microstrip Package

200 mil BeO Package



Typical Biasing Configuration



MSA-0520 Absolute Maximum Ratings

Parameter	Absolute Maximum ^[1]		
Device Current	225 mA		
Power Dissipation ^[2,3]	3.0 W		
RF Input Power	+25 dBm		
Junction Temperature	200°C		
Storage Temperature	−65 to 200°C		

Thermal Resistance^[2,4]:

 $\theta_{ic} = 25$ °C/W

- 1. Permanent damage may occur if any of these limits are exceeded.

- T_{CASE} = 25°C.
 Derate at 40 mW/°C for T_C > 125°C.
 The small spot size of this technique results in a higher, though more accurate determination of θ_{jc} than do alternate methods.

Electrical Specifications^[1], $T_A = 25^{\circ}C$

Symbol	Parameters and Test Conditions: $I_d = 165$ i	Units	Min.	Тур.	Max.	
P _{1 dB}	Output Power at 1 dB Gain Compression	f = 1.0 GHz	dBm	21.0	23.0	
G _P	Power Gain (S ₂₁ ²)	f = 0.1 GHz	dB	7.5	8.5	9.5
ΔG_P	Gain Flatness	f = 0.1 to 2.0 GHz	dB		±0.75	
f _{3 dB}	3 dB Bandwidth ^[2]		GHz		2.8	
VSWR —	Input VSWR	f = 0.1 to 2.0 GHz			2.0:1	
vovk —	Output VSWR	f = 0.1 to 2.0 GHz			2.5:1	
IP ₃	Third Order Intercept Point	f = 1.0 GHz	dBm		33.0	
NF _{50 Ω}	50 Ω Noise Figure	f = 1.0 GHz	dB		6.5	
t _D	Group Delay	f = 1.0 GHz	psec		170	
V _d	Device Voltage		V	10.5	12.0	13.5
dV/dT	Device Voltage Temperature Coefficient		mV/°C		-16.0	

- 1. The recommended operating current range for this device is 80 to 200 mA. Typical performance as a function of current is on the following page.
- 2. Referenced from 0.1 GHz Gain (GP).

MSA-0520 Typical Scattering Parameters ($T_A = 25^{\circ}C$, $I_d = 165$ mA)

Freq.	S-	11		S ₂₁			S ₁₂		S	22	
MHz	Mag	Ang	dB	Mag	Ang	dB	Mag	Ang	Mag	Ang	k
5	.57	-38	14.4	5.25	165	-19.4	.107	38	.67	-35	0.57
25	.25	-90	10.7	3.42	160	-14.9	.180	17	.29	-81	0.93
50	.15	-111	9.5	2.97	163	-14.4	.190	9	.18	-97	1.10
100	.11	-138	8.9	2.80	166	-14.2	.195	3	.11	-113	1.16
200	.10	-152	8.8	2.75	163	-14.1	.197	1	.10	-125	1.17
400	.10	-152	8.7	2.72	152	-14.1	.198	-2	.14	-123	1.16
600	.11	-147	8.6	2.70	140	-14.0	.199	-4	.18	-123	1.14
800	.13	-142	8.5	2.67	128	-14.1	.199	-6	.22	-127	1.12
1000	.15	-140	8.4	2.64	115	-14.1	.198	-8	.27	-131	1.09
1500	.22	-142	8.0	2.52	85	-13.7	.206	-12	.34	-143	0.98
2000	.30	-156	7.4	2.36	55	-13.3	.216	-16	.43	-158	0.85
2500	.37	-170	6.7	2.16	33	-12.9	.227	-18	.48	-166	0.75
3000	.41	170	5.6	1.91	8	-12.7	.232	-23	.51	-177	0.70
3500	.45	149	4.5	1.68	-16	-12.1	.249	-31	.55	173	0.63
4000	.46	124	3.3	1.45	-40	-11.7	.259	-39	.56	162	0.66

Typical Performance, $T_A = 25^{\circ}C$

(unless otherwise noted)

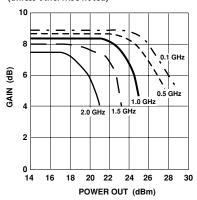


Figure 1. Typical Gain vs. Power Out, $T_A = 25^{\circ}\text{C}$, $I_d = 165 \text{ mA}$.

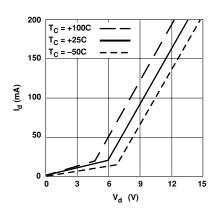


Figure 2. Device Current vs. Voltage.

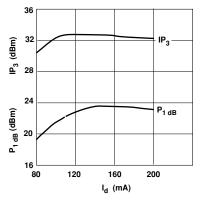


Figure 3. Output Power at 1 dB Gain Compression, Third Order Intercept vs. Current, f = 1.0 GHz.

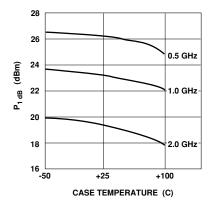


Figure 4. Output Power @ 1 dB Gain Compression vs. Temperature, $I_{\rm d}=$ 165 mA.

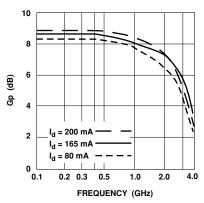


Figure 5. Gain vs. Frequency.

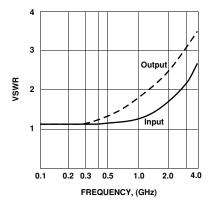


Figure 6. VSWR vs. Frequency, $I_d=165\ mA$.

Ordering Information

Part Numbers	No. of Devices	Comments
MSA-0520	100	Bulk

200 mil BeO Package Dimensions

